NSN 5961-01-364-9320

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-364-9320 **Inclosure Material:** Ceramic **Overall Length:** 0.750 inches **Overall Height:** Between 0.075 inches and 0.101 inches **Overall Width:** 0.390 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 drain to source voltage and -15.0 gate to source voltage and 25.0 gate to source voltage and 30.0 drain to substrate voltage and 20.0 source to substrate voltage and -0.3 gate to substrate voltage and 25.0 gate to substrate voltage **Current Rating Per Characteristic:** 50.00 milliamperes drain current **Power Rating Per Characteristic:** 300.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0